1GHz Triple Multiplexing Amplifiers

The ISL59424 and ISL59445 are 1GHz bandwidth multiplexing amplifiers designed primarily for video input switching. These MUX-amps exhibit a fixed gain of 1 and also feature a high speed three-state to enable the output of multiple devices to be wired together. All logic inputs have pull-downs to ground and may be left floating. The $\overline{EN}$ pin, when pulled high, sets the ISL59424 and ISL59445 in to low current mode - consuming just 15mW. An added feature in the ISL59424 is a latch enable function ($\overline{LE}$) that allows independent logic control using a common logic bus. When $\overline{LE}$ is high the last logic state is preserved.

TABLE 1. CHANNEL SELECT LOGIC TABLE ISL59424

S0	$\overline{\text{ENABLE}}$	HIZ	$\overline{\text{LE}}$	OUTPUT
0	0	0	0	IN0 (A, B, C)
1	0	0	0	IN1 (A, B, C)
X	1	X	X	Power Down
X	0	1	X	High Z
X	0	0	1	Last S0 State Preserved

TABLE 2. CHANNEL SELECT LOGIC TABLE ISL59445

S1	S0	$\overline{\text{ENABLE}}$	HIZ	OUTPUT
0	0	0	0	IN0 (A, B, C)
0	1	0	0	IN1 (A, B, C)
1	0	0	0	IN2 (A, B, C)
1	1	0	0	IN3 (A, B, C)
X	X	1	X	Power Down
X	X	0	1	High Z

Features

- Triple 2:1 and 4:1 Multiplexers for RGB
- Internally Set Gain-of-1
- High Speed Three-state Outputs (HIZ)
- Power-down Mode ($\overline{EN}$)
- Latch Enable (ISL59424)
- ±5V Operation
- ±1200 V/µsec Slew Rate
- 1GHz Bandwidth
- Latched Select Pin (ISL59424)
- Pb-Free Plus Anneal Available (RoHS Compliant)

Applications

- HDTV/DTV Analog Inputs
- Video Projectors
- Computer Monitors
- Set-top Boxes
- Security Video
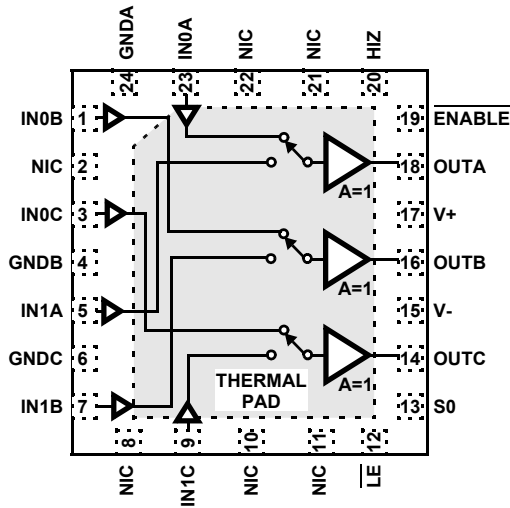- Broadcast Video Equipment

Ordering Information

PART NUMBER	PART MARKING	PACKAGE	TAPE & REEL	PKG. DWG. #
ISL59424IR	ISL59424IR	24 Ld QFN	-	MDP0046
ISL59424IR-T7	ISL59424IR	24 Ld QFN	7"	MDP0046
ISL59424IR-T13	ISL59424IR	24 Ld QFN	13"	MDP0046
ISL59424IRZ (Note)	ISL59424IRZ	24 Ld QFN (Pb-free)	-	MDP0046
ISL59424IRZ-T7 (Note)	ISL59424IRZ	24 Ld QFN (Pb-free)	7"	MDP0046
ISL59424IRZ-T13 (Note)	ISL59424IRZ	24 Ld QFN (Pb-free)	13"	MDP0046
ISL59445IR	ISL59445IR	32 Ld QFN*	-	MDP0046
ISL59445IR-T7	ISL59445IR	32 Ld QFN*	7"	MDP0046
ISL59445IR-T13	ISL59445IR	32 Ld QFN*	13"	MDP0046

*32 Ld QFN Exposed Pad Size 2.48 x 3.40mm
NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

Pinouts
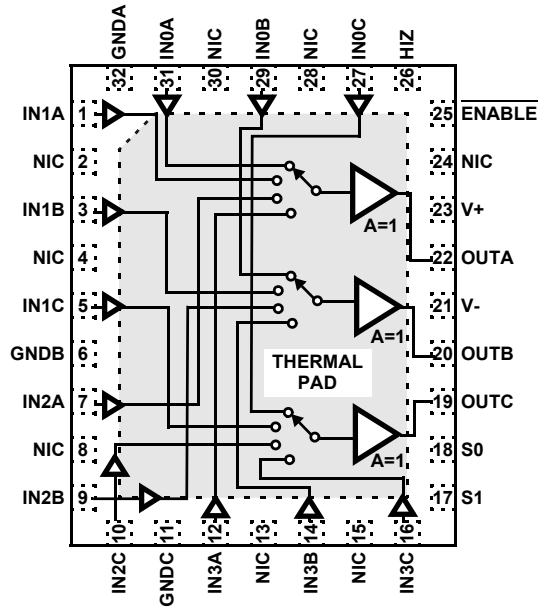
**ISL59424
(24-PIN QFN)**
TOP VIEW

GNDA 24 — IN0A 23 — NIC 22 — NIC 21 — HIZ 20

IN0B 1 — ENABLE 19
NIC 2 — OUTA 18 — A=1
IN0C 3 — V+ 17
GNDB 4 — OUTB 16 — A=1
IN1A 5 — V- 15
GNDC 6 — OUTC 14 — A=1
IN1B 7 — S0 13

THERMAL PAD

NIC 8 — IN1C 9 — NIC 10 — NIC 11 — LE 12

THERMAL PAD INTERNALLY CONNECTED TO V-. PAD MUST BE TIED TO V-

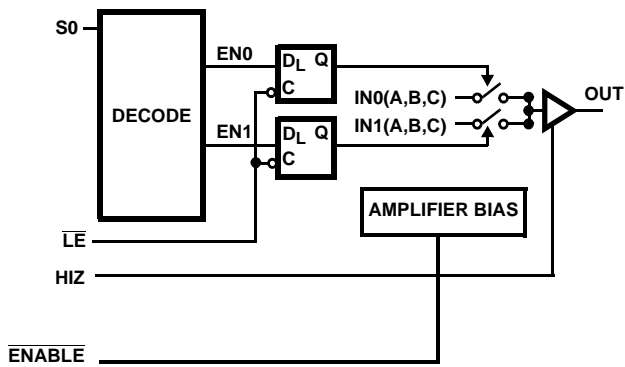LATCHED ON HIGH $\overline{\text{LE}}$

NIC = NO INTERNAL CONNECTION

**ISL59445
(32-PIN QFN)**
TOP VIEW

GNDA 32 — IN0A 31 — NIC 30 — IN0B 29 — NIC 28 — IN0C 27 — HIZ 26

IN1A 1 — ENABLE 25
NIC 2 — NIC 24
IN1B 3 — V+ 23 — A=1
NIC 4 — OUTA 22
IN1C 5 — V- 21 — A=1
GNDB 6 — OUTB 20
IN2A 7 — OUTC 19 — A=1
NIC 8 — S0 18
IN2B 9 — S1 17

THERMAL PAD

IN2C 10 — GNDC 11 — IN3A 12 — NIC 13 — IN3B 14 — NIC 15 — IN3C 16

THERMAL PAD INTERNALLY CONNECTED TO V-. PAD MUST BE TIED TO V-

NIC = NO INTERNAL CONNECTION

Functional Diagram ISL59424

S0 → DECODE → EN0 → D_L Q / C
EN1 → D_L Q / C
IN0(A,B,C)
IN1(A,B,C)
OUT
$\overline{\text{LE}}$
HIZ
AMPLIFIER BIAS
$\overline{\text{ENABLE}}$

A logic high on $\overline{\text{LE}}$ will latch the last S0 state. This logic state is preserved when cycling HIZ or $\overline{\text{ENABLE}}$ functions.

Functional Diagram ISL59445

S0 → DECODE
S1 → DECODE
EN0
EN1
EN2
EN3
IN0(A,B,C)
IN1(A,B,C)
IN2(A,B,C)
IN3(A,B,C)
OUT
HIZ
AMPLIFIER BIAS
$\overline{\text{ENABLE}}$

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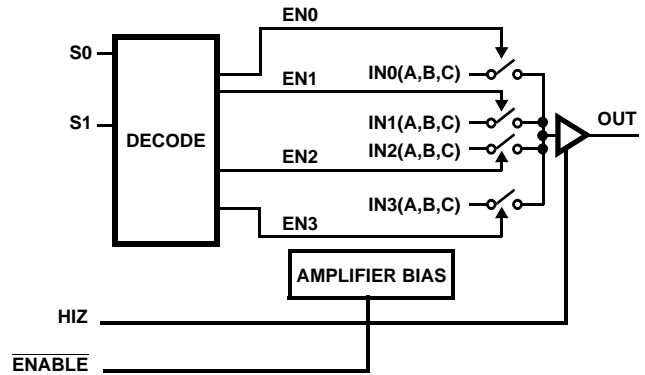
Absolute Maximum Ratings (T$_A$ = 25°C)

Supply Voltage (V+ to V-). 11V
Input Voltage . . . . V- -0.5V, V+ +0.5V
Supply Turn-on Slew Rate 1V/µs
Digital & Analog Input Current (Note 1) 50mA
Output Current (Continuous) 50mA
ESD Rating
  Human Body Model (Per MIL-STD-883 Method 3015.7). . . .2500V
  Machine Model 300V

Storage Temperature Range . . . .-65°C to +150°C
Ambient Operating Temperature . . . .-40°C to +85°C
Operating Junction Temperature . . . .-40°C to +125°C
Power Dissipation . . . . See Curves

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

1. If an input signal is applied before the supplies are powered up, the input current must be limited to these maximum values.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: T$_J$ = T$_C$ = T$_A$

Electrical Specifications
V+ = +5V, V- = -5V, GND = 0V, T$_A$ = 25°C, V$_{IN}$ = 1V$_{P-P}$ & R$_L$ = 500Ω to GND unless otherwise specified.

PARAMETER	DESCRIPTION	CONDITIONS	MIN	TYP	MAX	UNIT
GENERAL						
I$_S$ Enabled	Enabled Supply Current (ISL59424)	No load, V$_{IN}$ = 0V, Enable low, I$_S$+	35	39	43	mA
		No load, V$_{IN}$ = 0V, Enable low, I$_S$-	-40	-36	-32	mA
	Enabled Supply Current (ISL59445)	No load, V$_{IN}$ = 0V, Enable low, I$_S$+	47	53	60	mA
		No load, V$_{IN}$ = 0V, Enable low, I$_S$-	-57	-50	-44	mA
+I$_S$ Disabled	Disabled Supply Current	Enable High, I$_S$+	2	3	4	mA
		Enable High, I$_S$-	-50	0		µA
I$_b$	Input Bias Current	V$_{IN}$ = 0	-3.4	-2.2	-1.4	µA
I$_{TRI}$	Bias current into output, HIZ mode	ISL59424 - V$_{OUT}$ = +5V	8	15	22	µA
		ISL59445 - V$_{OUT}$ = 0V	-35	0	35	µA
V$_{OUT}$	Positive and Negative Output Swing	V$_{IN}$ = ±3.5V	±3.2	±3.4		V
I$_{OUT}$	Output Current	R$_L$ = 10Ω to GND	±80	±130		mA
V$_{OS}$	Offset Voltage		-13	3	13	mV
R$_{out}$	HIZ Output Resistance	HIZ = logic high		1.0		MΩ
R$_{out}$	Enabled Output Resistance	HIZ = logic low		0.2		Ω
R$_{IN}$	Input Resistance	V$_{IN}$ = ±3.5V		10		MΩ
A$_{CL}$ or A$_V$	Voltage Gain	V$_{IN}$ = ±1.5V	0.98	0.99	1.0	V/V
LOGIC						
V$_{IH}$	Input High Voltage (Logic Inputs)		2			V
V$_{IL}$	Input Low Voltage (Logic Inputs)				0.8	V
I$_{IH}$	Input High Current (Logic Inputs)	V$_H$ = 5V	235	270	320	µA
I$_{IL}$	Input Low Current (Logic Inputs)	V$_L$ = 0V		1	3	µA
AC GENERAL						
PSRR	Power Supply Rejection Ratio (ISL59424)	DC, PSRR V+ & V- combined	60	73		dB
	Power Supply Rejection Ratio (ISL59445)	DC, PSRR V+ & V- combined	50	57		dB
ISO	Channel Isolation (ISL59424)	f = 10MHz, C$_L$ = 0.5pF, V$_{IN}$ = -6dBm		80		dB
	Channel Isolation (ISL59445)			75		dB

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Electrical Specifications   V+ = +5V, V- = -5V, GND = 0V, T_A = 25°C, V_{IN} = 1V_{P-P} & R_L = 500Ω to GND unless otherwise specified.

PARAMETER	DESCRIPTION	CONDITIONS	MIN	TYP	MAX	UNIT
Xtalk	Channel Cross Talk (ISL59424)	f = 10MHz, C_L = 0.5pF, V_{IN} = -6dBm		75		dB
	Channel Cross Talk (ISL59445)			70		
dG	Differential Gain Error	NTC-7, RL = 150, C_L = 0.5pF		0.02		%
dP	Differential Phase Error	NTC-7, RL = 150, C_L = 0.5pF		0.02		°
BW	-3dB Bandwidth	C_L = 0.5pF		1000		MHz
FBW	0.1dB Bandwidth	C_L = 0.5pF		130		MHz
	0.1dB Bandwidth	CL = 1.5pF		200		MHz
SWITCHING CHARACTERISTICS						
SR	Slew Rate	25% to 75%, R_L = 150Ω, Input Enabled, C_L = 1.5pF, V_{IN} = ±1V		±1200		V/µs
V_{GLITCH} ISL58424	Channel -to-Channel Switching Glitch	V_{IN} = 0V, C_L = 0.5pF		40		mV_{P-P}
	$\overline{Enable}$ Switching Glitch	V_{IN} = 0V, C_L = 0.5pF		300		mV_{P-P}
	HIZ Switching Glitch	V_{IN} = 0V, C_L = 0.5pF		200		mV_{P-P}
V_{GLITCH} ISL59445	Channel -to-Channel Switching Glitch	V_{IN} = 0V, C_L = 0.5pF		20		mV_{P-P}
	$\overline{Enable}$ Switching Glitch	V_{IN} = 0V, C_L = 0.5pF		200		mV_{P-P}
	HIZ Switching Glitch	V_{IN} = 0V, C_L = 0.5pF		200		mV_{P-P}
t_{SW-L-H}	Channel Switching Time Low to High	1.2V logic threshold to 10% movement of analog output		15		ns
t_{SW-H-L}	Channel Switching Time High to Low	1.2V logic threshold to 10% movement of analog output		15		ns
tr	Rise Time	10% to 90%		600		ps
tf	Fall Time	10% to 10%		800		ps
tpd	Propagation Delay	10% to 10%		600		ps
t_S	0.1% Settling Time	Step = 1V		6		ns
t_{LH}	Latch Enable HoldTime	$\overline{LE}$ = 0V		10		ns

Typical Performance Curves V_S = ±5V, R_L = 500Ω to GND, T_A = 25°C, unless otherwise specified.
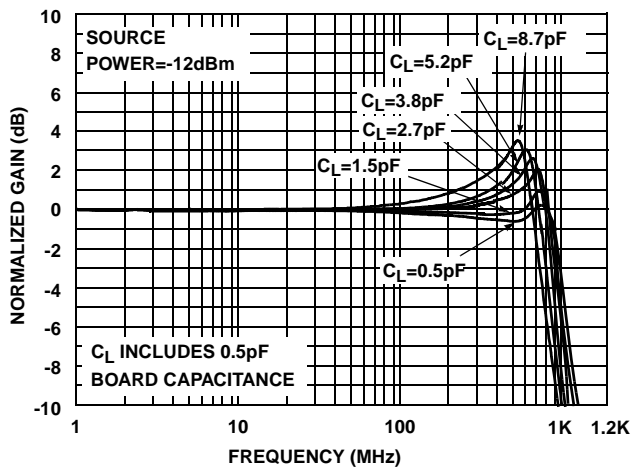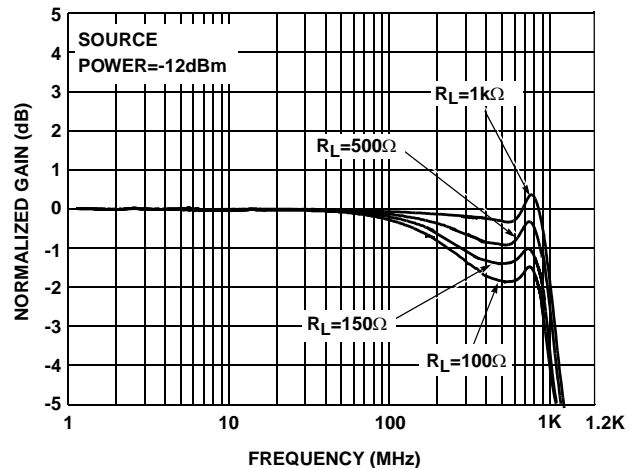

FIGURE 1. GAIN vs FREQUENCY vs C_L

FIGURE 2. GAIN vs FREQUENCY vs R_L

Typical Performance Curves $V_S = \pm 5V$, $R_L = 500\Omega$ to GND, $T_A = 25°C$, unless otherwise specified. **(Continued)**
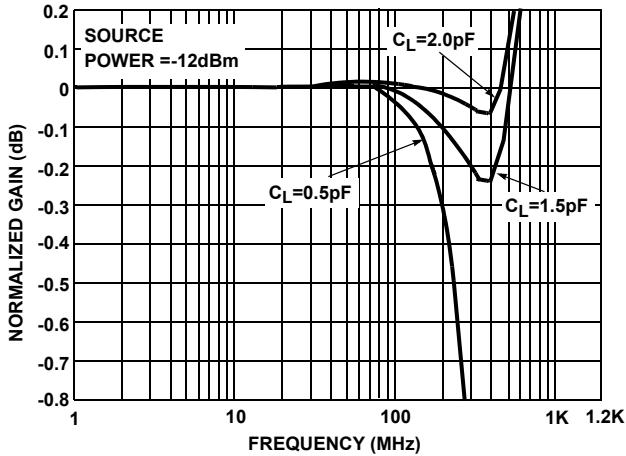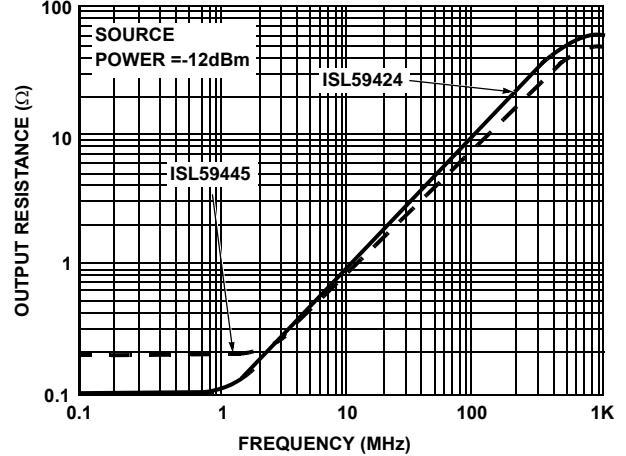
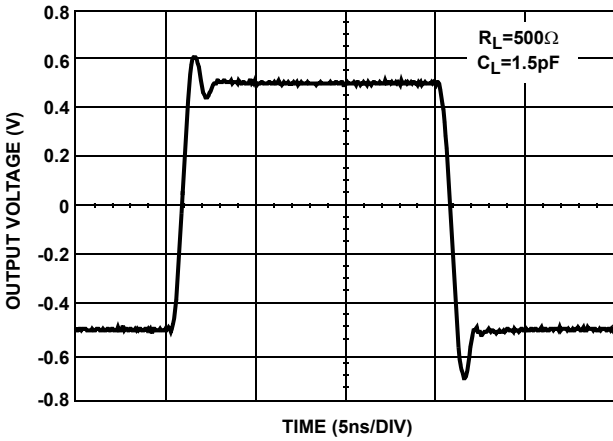FIGURE 3. 0.1dB GAIN vs FREQUENCY

FIGURE 4. R_{OUT} vs FREQUENCY

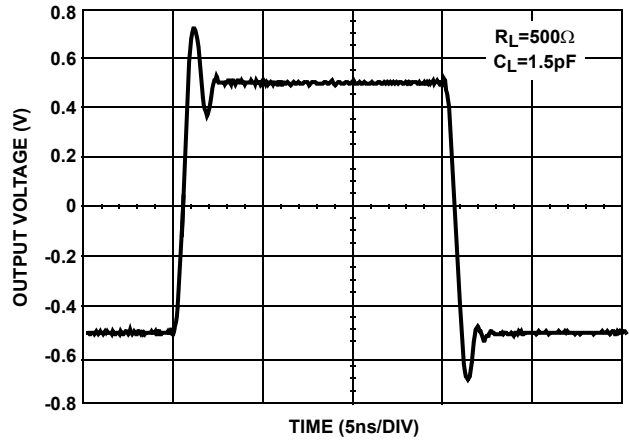FIGURE 5. ISL59424 TRANSIENT RESPONSE
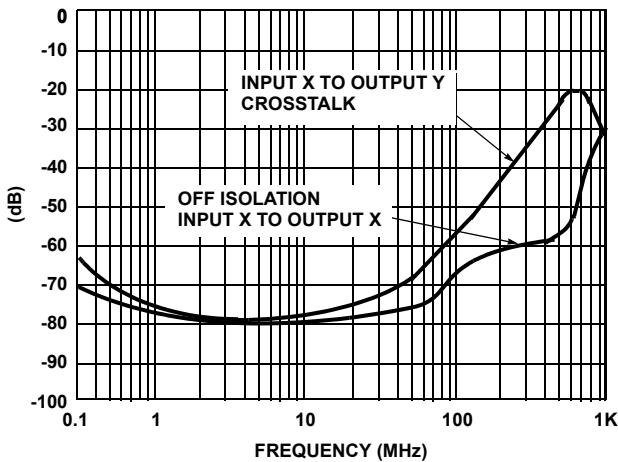
FIGURE 6. ISL59445 TRANSIENT RESPONSE
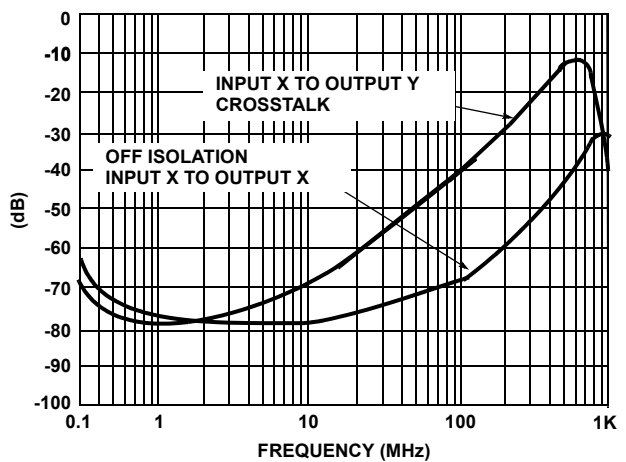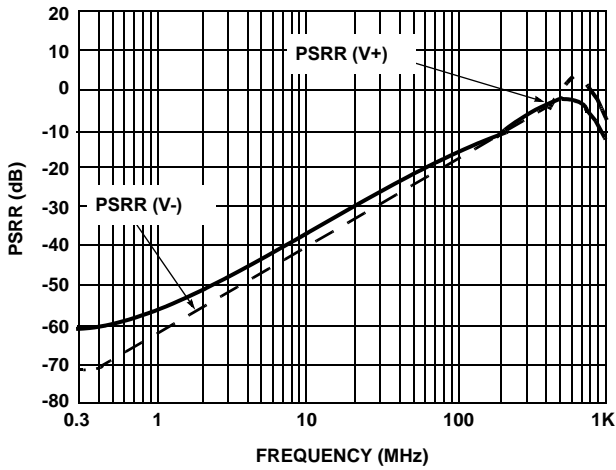
FIGURE 7. ISL59424 CROSSTALK AND OFF ISOLATION

FIGURE 8. ISL59445 CROSSTALK AND OFF ISOLATION

Typical Performance Curves $V_S = \pm 5V$, $R_L = 500\Omega$ to GND, $T_A = 25°C$, unless otherwise specified. **(Continued)**

FIGURE 9. ISL59424 PSRR CHANNELS A, B, C
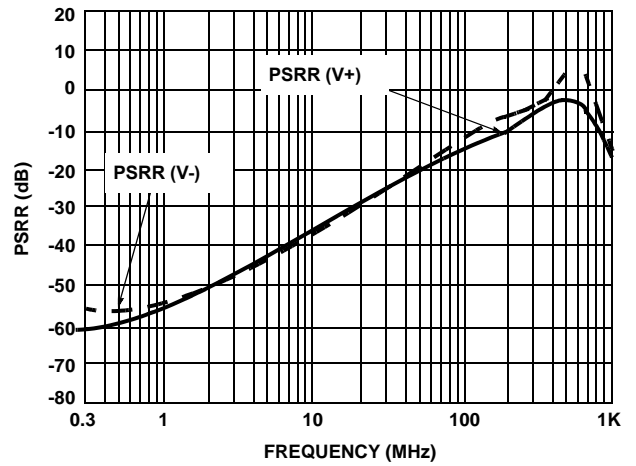
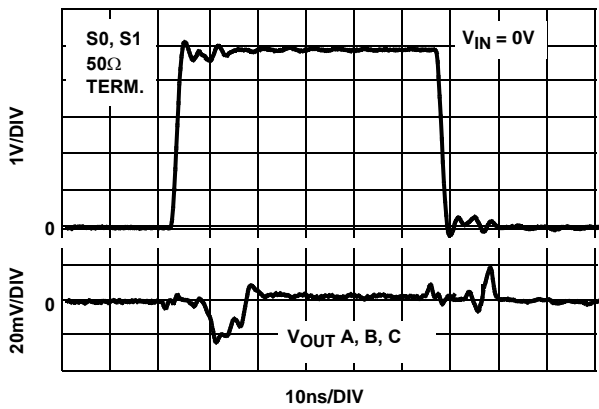FIGURE 10. ISL59445 PSRR CHANNELS A, B, C

FIGURE 11. CHANNEL TO CHANNEL SWITCHING GLITCH
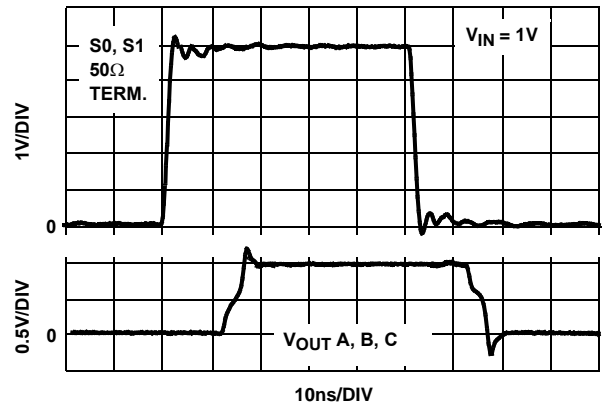$V_{IN} = 0V$

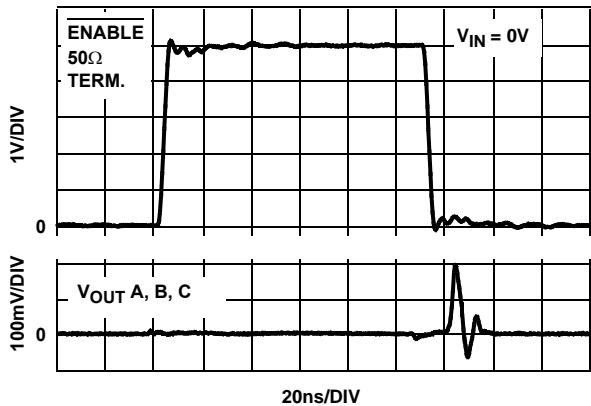FIGURE 12. CHANNEL TO CHANNEL TRANSIENT RESPONSE
$V_{IN} = 1V$
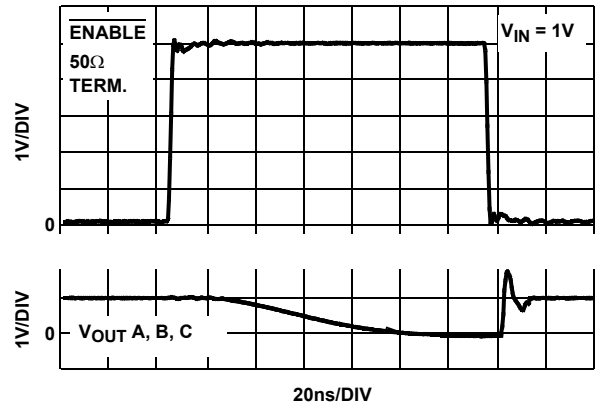

FIGURE 13. ENABLE SWITCHING GLITCH $V_{IN} = 0V$

FIGURE 14. ENABLE TRANSIENT RESPONSE $V_{IN} = 1V$

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Typical Performance Curves V_S = ±5V, R_L = 500Ω to GND, T_A = 25°C, unless otherwise specified. **(Continued)**
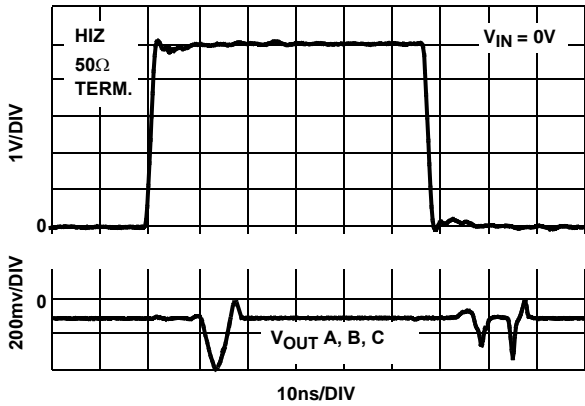

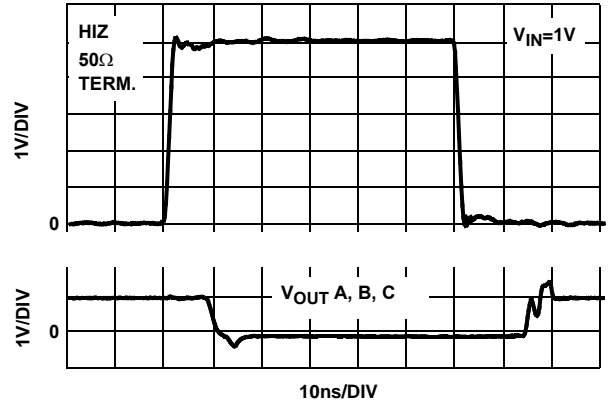FIGURE 15. HIZ SWITCHING GLITCH V_{IN} = 0V

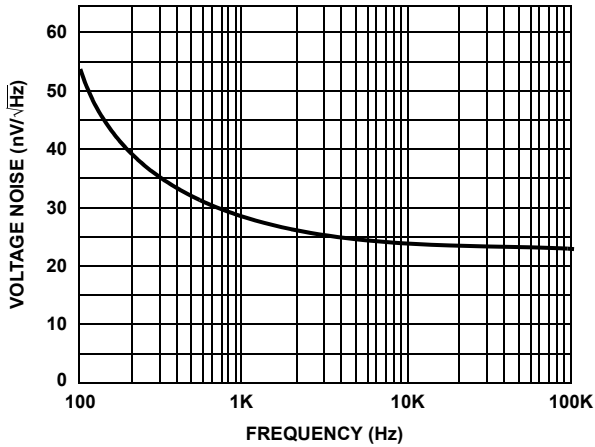FIGURE 16. HIZ TRANSIENT RESPONSE V_{IN} = 1V
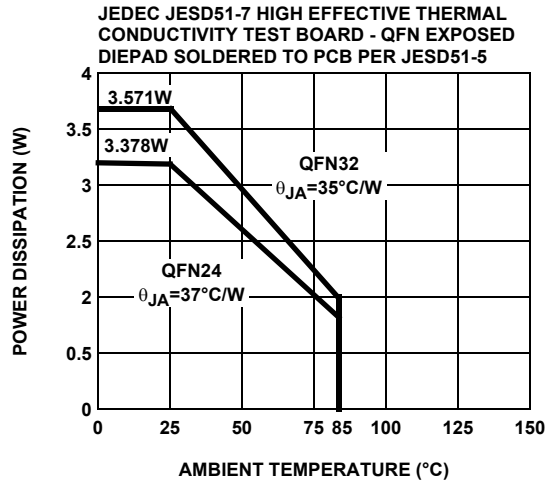

FIGURE 17. INPUT NOISE vs FREQUENCY (OUTPUT A, B, C)

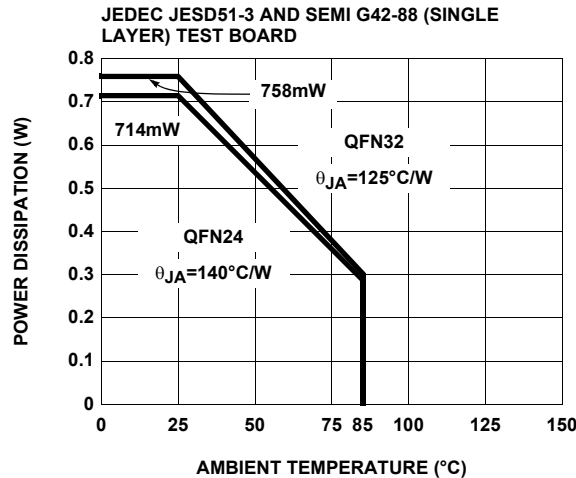FIGURE 18. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE

FIGURE 19. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE
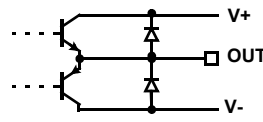
Pin Descriptions

ISL59445 (32-PIN QFN)	ISL59424 (24-PIN QFN)	PIN NAME	EQUIVALENT CIRCUIT	DESCRIPTION
1	5	IN1A	Circuit 1.	Channel 1 input for output amplifier "A"
2, 4, 8, 13, 15, 24, 28, 30	2, 8, 10, 11, 21, 22	NIC		**N**ot **I**nternally **C**onnected; it is recommended these pins be tied to ground to minimize crosstalk.
3	7	IN1B	Circuit 1.	Channel 1 input for output amplifier "B"
5	9	IN1C	Circuit 1.	Channel 1 input for output amplifier "C"
6	4	GNDB	Circuit 4.	Ground pin for output amplifier "B"
7		IN2A	Circuit 1.	Channel 2 input for output amplifier "A"
9		IN2B	Circuit 1.	Channel 2 input for output amplifier "B"
10		IN2C	Circuit 1.	Channel 2 input for output amplifier "C"
11	6	GNDC	Circuit 4.	Ground pin for output amplifier "C"
12		IN3A	Circuit 1.	Channel 3 input for output amplifier "A"
14		IN3B	Circuit 1.	Channel 3 input for output amplifier "B"
16		IN3C	Circuit 1.	Channel 3 input for output amplifier "C"
17		S1	Circuit 2.	Channel selection pin MSB (binary logic code)
18	13	S0	Circuit 2.	Channel selection pin. LSB (binary logic code)
19	14	OUTC	Circuit 3.	Output of amplifier "C"
20	16	OUTB	Circuit 3.	Output of amplifier "B"
21	15	V-	Circuit 4.	Negative power supply
22	18	OUTA	Circuit 3.	Output of amplifier "A"
23	17	V+	Circuit 4.	Positive power supply
25	19	$\overline{\text{ENABLE}}$	Circuit 2.	Device enable (active low). Internal pull-down resistor ensures the device will be active with no connection to this pin. A logic High on this pin puts device into power-down mode. In power-down mode only logic circuitry is active. All logic states are preserved post power-down. This state is not recommended for logic control where more than one MUX-amp share the same video output line.
	12	$\overline{\text{LE}}$	Circuit 2.	Device latch enable on the ISL59424. A logic high on $\overline{\text{LE}}$ will latch the last (S0, S1) logic state. HIZ and $\overline{\text{ENABLE}}$ functions are not latched with the $\overline{\text{LE}}$ pin.
26	20	HIZ	Circuit 2.	Output disable (active high). Internal pull-down resistor ensures the device will be active with no connection to this pin. A logic high, puts the outputs in a high impedance state. Use this state to control logic when more than one MUX-amp share the same video output line.
27	3	IN0C	Circuit 1.	Channel 0 for output amplifier "C"
29	1	IN0B	Circuit 1.	Channel 0 for output amplifier "B"
31	23	IN0A	Circuit 1.	Channel 0 for output amplifier "A"
32	24	GNDA	Circuit 4.	Ground pin for output amplifier "A"
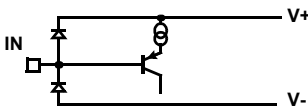
CIRCUIT 1
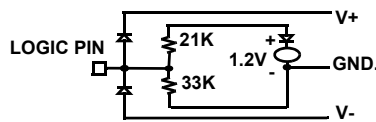
CIRCUIT 2

CIRCUIT 3

CIRCUIT 4

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September 8, 2005
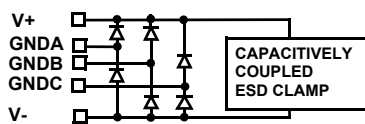
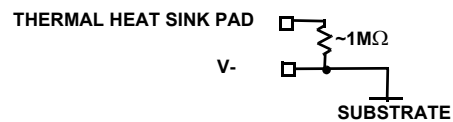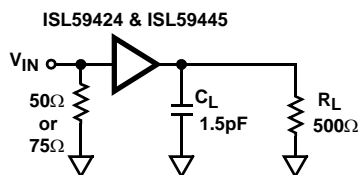## AC Test Circuits

FIGURE 20A. TEST CIRCUIT WITH OPTIMAL OUTPUT LOAD
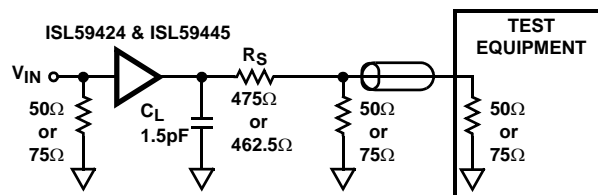

FIGURE 20B. TEST CIRCUIT FOR MEASURING WITH 50Ω OR 75Ω INPUT TERMINATED EQUIPMENT
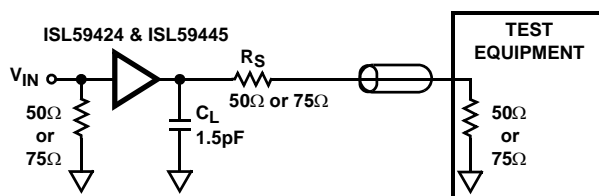

FIGURE 20C. BACKLOADED TEST CIRCUIT FOR VIDEO CABLE APPLICATION. BANDWIDTH AND LINEARITY FOR R_L LESS THAN 500Ω WILL BE DEGRADED.

FIGURE 20. TEST CIRCUITS

Figure 20A illustrates the optimum output load for testing AC performance. Figure 20B illustrates the optimum output load when connecting to 50Ω input terminated equipment.

Application Information

General

The ISL59424 and ISL59445 are triple 2:1 and 4:1 muxes that are ideal for the matrix element of high performance switchers and routers. The ISL59424 and ISL59445 are optimized to drive a 1.5pF in parallel with a 500Ω load. The capacitance can be split between the PCB capacitance an and external load capacitance. Their low input capacitance and high input resistance provide excellent 50Ω or 75Ω terminations.

Ground Connections

For the best isolation and crosstalk rejection, all GND pins and NIC pins must connect to the GND plane.

Control Signals

S0, S1, ENABLE, LE, HIZ - These pins are binary coded, TTL/CMOS compatible control inputs. The S0, S1 pins select which one of the inputs connect to the output. All three amplifiers are switched simultaneously from their respective inputs. The ENABLE, LE, HIZ pins are used to disable the part to save power, latch in the last logic state and three-state the output amplifiers, respectively. For control signal rise and fall times less than 10ns the use of termination resistors close to the part should be considered to minimize transients coupled to the output.

Power-Up Considerations

The ESD protection circuits use internal diodes from all pins the V+ and V- supplies. In addition, a dV/dT- triggered clamp is connected between the V+ and V- pins, as shown in the Equivalent Circuits 1 through 4 section of the Pin Description table. The dV/dT triggered clamp imposes a maximum supply turn-on slew rate of 1V/μs. Damaging currents can flow for power supply rates-of-rise in excess of 1V/μs, such as during hot plugging. Under these conditions, additional methods should be employed to ensure the rate of rise is not exceeded.

Consideration must be given to the order in which power is applied to the V+ and V- pins, as well as analog and logic input pins. Schottky diodes (Motorola MBR0550T or equivalent) connected from V+ to ground and V- to ground (Figure 21) will shunt damaging currents away from the internal V+ and V- ESD diodes in the event that the V+ supply is applied to the device before the V- supply.

If positive voltages are applied to the logic or analog video input pins before V+ is applied, current will flow through the internal ESD diodes to the V+ pin. The presence of large decoupling capacitors and the loading effect of other circuits connected to V+, can result in damaging currents through the ESD diodes and other active circuits within the device. Therefore, adequate current limiting on the digital and analog inputs is needed to prevent damage during the time the voltages on these inputs are more positive than V+.
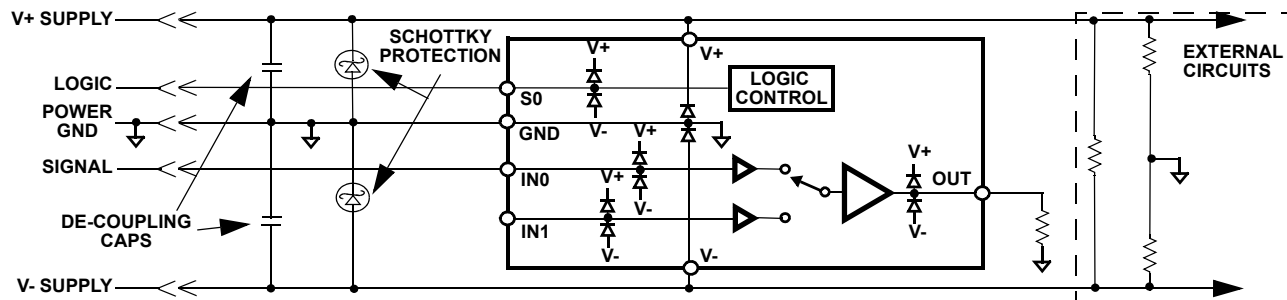
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FIGURE 21. SCHOTTKY PROTECTION CIRCUIT

HIZ State

An internal pull-down resistor connected to the HIZ pin ensures the device will be active with no connection to the HIZ pin. The HIZ state is established within approximately 15ns (Figure 16) by placing a logic high (>2V) on the HIZ pin. If the HIZ state is selected, the output is a high impedance 1.4MΩ with approximately 1.5pF in parallel with a 10μA bias current from the output. Use this state to control the logic when more than one mux shares a common output.

In the HIZ state the output is three-stated, and maintains its high Z even in the presence of high slew rates. The supply current during this state is basically the same as the active state.

$\overline{ENABLE}$ and Power Down States

The enable pin is active low. An internal pull-down resistor ensures the device will be active with no connection to the $\overline{ENABLE}$ pin. The Power Down state is established within approximately 100ns (Figure 14), if a logic high (>2V) is placed on the $\overline{ENABLE}$ pin. In the Power Down state, the output has no leakage but has a large variable capacitance (on the order of 15pF), and is capable of being back-driven. Under this condition, large incoming slew rates can cause fault currents of tens of mA. **Do not use this state as a logic control for applications driving more than one mux on a common output.**

$\overline{LE}$ State

The ISL59424 is equipped with a Latch Enable pin. A logic high (>2V) on the $\overline{LE}$ pin latches the last logic state. This logic state is preserved when cycling HIZ or $\overline{ENABLE}$ functions.

Limiting the Output Current

No output short circuit current limit exists on these parts. All applications need to limit the output current to less than 50mA. Adequate thermal heat sinking of the parts is also required.

Application Example

Figure 21 illustrates the use of the ISL59445, two ISL84517 SPST switches and one NC7ST00P5X NAND gate to mux 3 different component video signals and one RGB video signal. The SPDT switches provide the sync signal for the RGB video and disconnects the sync signal for the component signal.

PC Board Layout

The frequency response of this circuit depends greatly on the care taken in designing the PC board. The following are recommendations to achieve optimum high frequency performance from your PC board.

- The use of low inductance components such as chip resistors and chip capacitors is strongly recommended.

- Minimize signal trace lengths. Trace inductance and capacitance can easily limit circuit performance. Avoid sharp corners, use rounded corners when possible. Vias in the signal lines add inductance at high frequency and should be avoided. PCB traces greater than 1" begin to exhibit transmission line characteristics with signal rise/fall times of 1ns or less. High frequency performance may be degraded for traces greater than one inch, unless strip line are used.

- Match channel-channel analog I/O trace lengths and layout symmetry. This will minimize propagation delay mismatches.

- Maximize use of AC de-coupled PCB layers. All signal I/O lines should be routed over continuous ground planes (i.e. no split planes or PCB gaps under these lines). Avoid vias in the signal I/O lines.

- Use proper value and location of termination resistors. Termination resistors should be as close to the device as possible.

- When testing use good quality connectors and cables, matching cable types and keeping cable lengths to a minimum.

- Minimum of 2 power supply de-coupling capacitors are recommended (1000pF, 0.01μF) as close to the devices as possible - Avoid vias between the cap and the device because vias add unwanted inductance. Larger caps can be farther away. When vias are required in a layout, they should be routed as far away from the device as possible.

- The NIC pins are placed on both sides of the input pins. These pins are not internally connected to the die. It is recommended these pins be tied to ground to minimize crosstalk.

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The QFN Package Requires Additional PCB Layout Rules for the Thermal Pad

The thermal pad is electrically connected to V- supply through the high resistance IC substrate. Its primary function is to provide heat sinking for the IC. However, because of the connection to the V- supply through the substrate, the thermal pad must be tied to the V- supply to prevent unwanted current flow to the thermal pad. Do **not** tie this pin to GND. Connecting this pin to GND could result in large back biased currents flowing between GND and V-. The ISL59445 uses the package with pad dimensions of D2 = 2.48mm and E2 = 3.4mm.

Maximum AC performance is achieved if the thermal pad is attached to a dedicated de-coupled layer in a multi-layered PC board. In cases where a dedicated layer is not possible, AC performance may be reduced at upper frequencies.

The thermal pad requirements are proportional to power dissipation and ambient temperature. A dedicated layer eliminates the need for individual thermal pad area. When a dedicated layer is not possible a 1" x 1" pad area is sufficient for the ISL59445 that is dissipating 0.5W in +50°C ambient. Pad area requirements should be evaluated on a case by case basis.
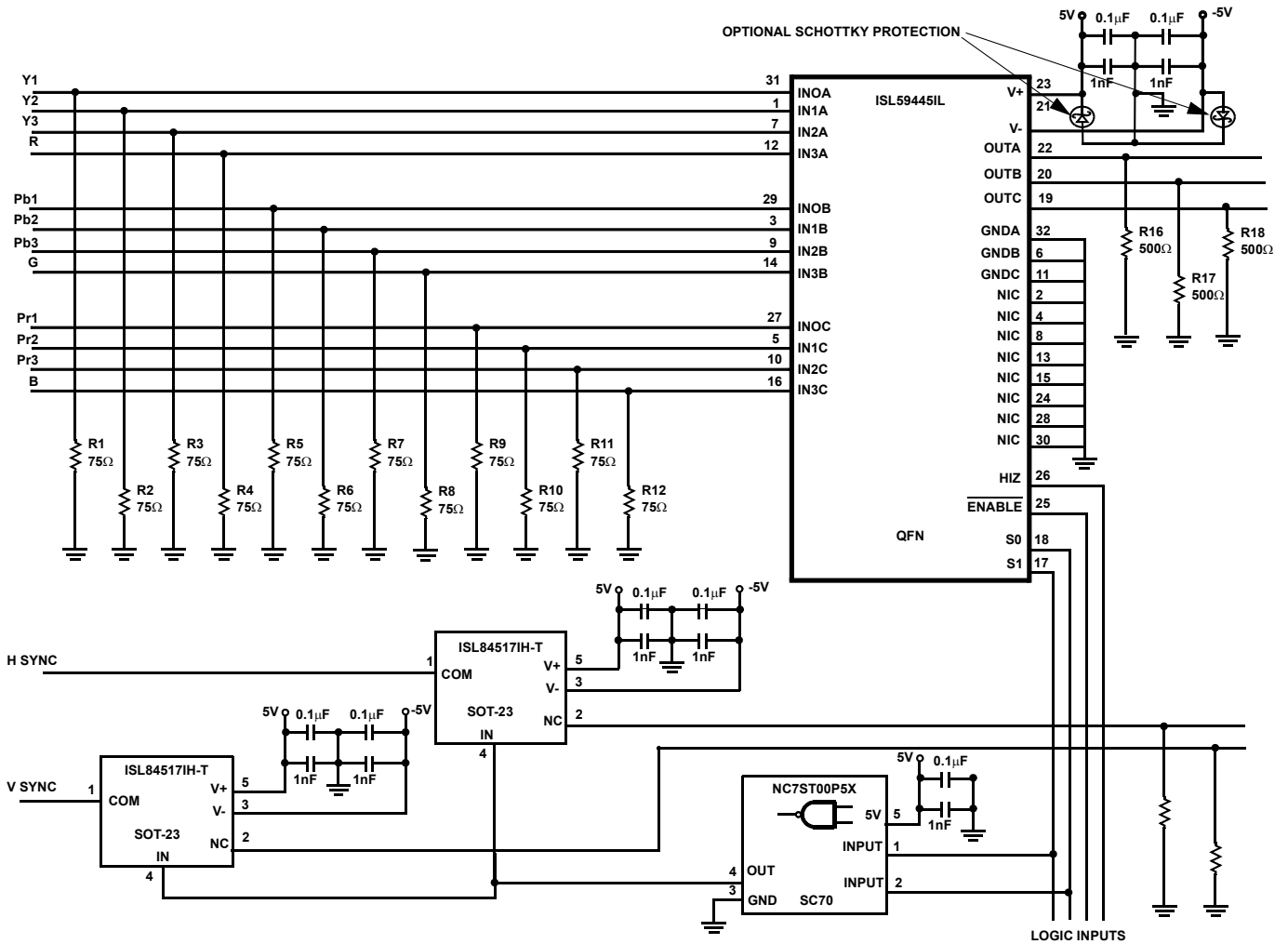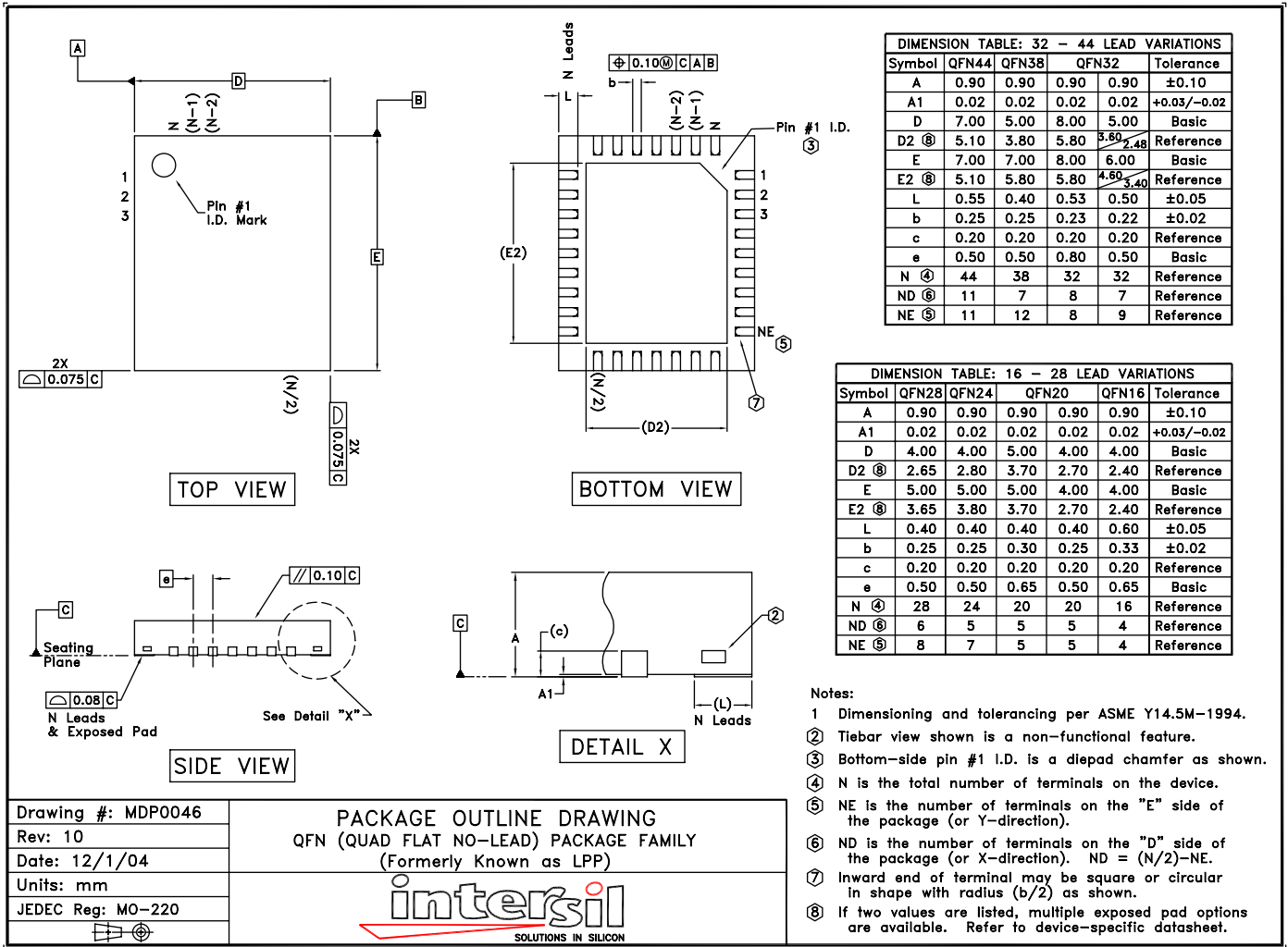
FIGURE 22. APPLICATION SHOWING THREE YPBPR CHANNELS AND ONE RGB+HV CHANNEL

QFN Package Outline Drawing

TOP VIEW

BOTTOM VIEW

SIDE VIEW

DETAIL X

DIMENSION TABLE: 32 – 44 LEAD VARIATIONS

Symbol	QFN44	QFN38	QFN32		Tolerance
A	0.90	0.90	0.90	0.90	±0.10
A1	0.02	0.02	0.02	0.02	+0.03/−0.02
D	7.00	5.00	8.00	5.00	Basic
D2 ⑧	5.10	3.80	5.80	3.60/2.48	Reference
E	7.00	7.00	8.00	6.00	Basic
E2 ⑧	5.10	5.80	5.80	4.60/3.40	Reference
L	0.55	0.40	0.53	0.50	±0.05
b	0.25	0.25	0.23	0.22	±0.02
c	0.20	0.20	0.20	0.20	Basic
e	0.50	0.50	0.80	0.50	Basic
N ④	44	38	32	32	Reference
ND ⑥	11	7	8	7	Reference
NE ⑤	11	12	8	9	Reference

DIMENSION TABLE: 16 – 28 LEAD VARIATIONS

Symbol	QFN28	QFN24	QFN20		QFN16	Tolerance
A	0.90	0.90	0.90	0.90	0.90	±0.10
A1	0.02	0.02	0.02	0.02	0.02	+0.03/−0.02
D	4.00	4.00	5.00	4.00	4.00	Basic
D2 ⑧	2.65	2.80	3.70	2.70	2.40	Reference
E	5.00	5.00	5.00	4.00	4.00	Basic
E2 ⑧	3.65	3.80	3.70	2.70	2.40	Reference
L	0.40	0.40	0.40	0.40	0.60	±0.05
b	0.25	0.25	0.30	0.25	0.33	±0.02
c	0.20	0.20	0.20	0.20	0.20	Reference
e	0.50	0.50	0.65	0.50	0.65	Basic
N ④	28	24	20	20	16	Reference
ND ⑥	6	5	5	5	4	Reference
NE ⑤	8	7	5	5	4	Reference

Notes:
1. Dimensioning and tolerancing per ASME Y14.5M−1994.
② Tiebar view shown is a non−functional feature.
③ Bottom−side pin #1 I.D. is a diepad chamfer as shown.
④ N is the total number of terminals on the device.
⑤ NE is the number of terminals on the "E" side of the package (or Y−direction).
⑥ ND is the number of terminals on the "D" side of the package (or X−direction).   ND = (N/2)−NE.
⑦ Inward end of terminal may be square or circular in shape with radius (b/2) as shown.
⑧ If two values are listed, multiple exposed pad options are available. Refer to device−specific datasheet.

Drawing #: MDP0046	PACKAGE OUTLINE DRAWING
Rev: 10	QFN (QUAD FLAT NO−LEAD) PACKAGE FAMILY
Date: 12/1/04	(Formerly Known as LPP)
Units: mm	
JEDEC Reg: MO−220	*intersil*
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NOTE: The package drawing shown here may not be the latest version. To check the latest revision, please refer to the Intersil website at <http://www.intersil.com/design/packages/index.asp>

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